



# Semiconducting silicon–phosphorus frameworks for caging exotic polycations†

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**A series of novel semiconductors  $AAe_6Si_{12}P_{20}X$  ( $A = Na, K, Rb, Cs$ ;  $Ae = Sr, Ba$ ;  $X = Cl, Br, I$ ) is reported. Their crystal structures feature a tetrahedral Si–P framework with large zeolite-like pores hosting two types of cations, monoatomic  $A^+$  and unprecedented octahedral  $X@Ae_6^{11+}$ . Mixing of the A and Ba cations was detected by single crystal X-ray diffraction and confirmed by multinuclear solid state NMR. The reported compounds are highly stable semiconductors with a bandgap range from 1.4 to 2.0 eV.**

Semiconductors are of vital importance in modern society. Due to their many applications, the synthesis of novel semiconducting phases with specific properties is a commendable goal. However, rational design is challenging, and each application specifies additional requirements for the material. For example, photovoltaics require the band gap of the semiconductor to be between 1 and 2 eV to maximize absorption of the visible spectra.<sup>1,2</sup> Photocatalysts additionally require proper alignment of the valence and conduction bands based on the redox potential of the targeted reaction.<sup>3</sup> For hard radiation detection, semiconductors must have a suitable band gap (1.5 to 2.4 eV) as well as a high crystal density.<sup>4</sup> For nonlinear optical materials, the compound must have a noncentrosymmetric structure, suitable band gap, and high laser damage threshold.<sup>5,6</sup> A common requirement for almost all applications is stability in a number of conditions (ambient conditions, pressure, humidity, radiation, temperature, etc.). In terms of semiconductors based on earth-abundant silicon and phosphorus, binary SiP and SiP<sub>2</sub> exhibited high carrier mobilities and high stability.<sup>7</sup> Orthorhombic SiP (*Cmc*<sub>2</sub>) has a layered crystal structure with a band gap of around 1.7 eV.<sup>8</sup> Bulk and monolayer SiP hold promise for photodetection as well as nonlinear optics.<sup>9,10</sup> SiP<sub>2</sub> has been predicted to be a

stable 2D material.<sup>11</sup> Ternary Si–P semiconductors, such as Ba<sub>2</sub>Si<sub>3</sub>P<sub>6</sub>, MgSiP<sub>2</sub>, ZnSiP<sub>2</sub>, CdSiP<sub>2</sub>, IrSi<sub>3</sub>P<sub>3</sub>, RuSi<sub>4</sub>P<sub>4</sub>, and BaSi<sub>7</sub>P<sub>10</sub>, exhibit a diverse variety of the silicon–phosphorus bonding motifs.<sup>12–17</sup> The compositional space of phosphides is less explored than the oxide and chalcogenide phase spaces, thus making it an underexplored frontier for finding new semiconductors.

This work originated from pursuing development of the flux synthesis for Si- and P-containing materials. The requirements that must be considered for flux growth are extensive.<sup>18</sup> The combination of Si and P presents additional challenges when considering the typical approaches used for the constituents individually. While flux growth of silicides can be performed using Al, Ga, and In fluxes,<sup>19</sup> the potential formation of AlP, GaP, and InP is undesirable. Sn is a great choice of flux for P containing materials, but Si has a low solubility in Sn, making Sn an undesirable choice. A less traditional flux choice is the salt flux,<sup>20</sup> which has been employed in silicates, germanates, and P-containing thiophosphates.<sup>21</sup> Salt fluxes have been shown to promote the formation of highly complex crystal structures with multiple elements (quaternary and beyond).<sup>22</sup> As a result of using salt flux, new salt inclusion semiconductors, AAe<sub>6</sub>Si<sub>12</sub>P<sub>20</sub>X ( $A = Na, K, Rb, Cs$ ;  $Ae = Sr, Ba$ ;  $X = Cl, Br, I$ ) were synthesized.

Initially, a reaction at 950 °C intended for crystal growth of BaCuSi<sub>2</sub>P<sub>3</sub><sup>23</sup> with excess P and excess CsBr/CsI mixture resulted in the formation of CsBa<sub>6</sub>Si<sub>12</sub>P<sub>20</sub>Br<sub>1-x</sub>I<sub>x</sub>. Large cuboidal single crystals with a deep red color were selected from the walls of the ampoule for single crystal X-ray diffraction (SXRD) (Fig. S1, ESI†). After the initial discovery, syntheses targeting the formation of AAe<sub>6</sub>Si<sub>12</sub>P<sub>20</sub>X were carried out in similar conditions. These compounds can be made directly from the combination of the AX salt, Ae metal, Si, and P in the stoichiometric ratios (Fig. S2, ESI†). Alternatively, crystals suitable for SXRD can be grown with the addition of excess salt (Table S1, ESI†). The phase pure material CsBa<sub>6</sub>Si<sub>12</sub>P<sub>20</sub>Cl is air-stable at room temperature on the order of weeks, water-stable, and stable up to 500 °C in air for at least 2 hours. CsBa<sub>6</sub>Si<sub>12</sub>P<sub>20</sub>X does not melt below 1100 °C as evidenced by differential scanning calorimetry

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(Fig. S8, ESI<sup>†</sup>). So far, the crystal structures of 11 isostructural compounds have been determined (Table S3, ESI<sup>†</sup>).  $\text{AAe}_6\text{Si}_{12}\text{P}_{20}\text{X}$  compounds adopt a novel crystal structure type and exhibit exotic polycations  $[\text{Ae}_6\text{X}]^{11+}$ . Octahedral polycations such as  $\text{Cs}_6\text{F}$  have been observed in  $[\text{Cs}_6\text{F}][\text{Cs}_3\text{AgF}][\text{Ge}_{14}\text{O}_{32}]$  as well as cesium halide uranyl silicates.<sup>24,25</sup> However, the formal polycationic charge of  $\text{Cs}_6\text{F}$  is +5, which is less than half of what is expected for  $\text{Ba}_6\text{Cl}$  (+11). To our knowledge, there are no reports of a salt inclusion compound containing such a cationic fragment. Out of 11 synthesized isostructural compounds  $\text{AAe}_6\text{Si}_{12}\text{P}_{20}\text{X}$ , we will focus on  $\text{CsBa}_6\text{Si}_{12}\text{P}_{20}\text{Cl}$  which crystallizes in the space group  $Fm\bar{3}m$  (No. 225) with a Wyckoff sequence of *igfeba*, which is a new structure type. The large charge of the  $[\text{Ae}_6\text{X}]^{11+}$  polycation attests to the ability of silicon–phosphorus frameworks to accommodate charge. Silicon phosphides have been shown to accommodate charges from cations by adapting the bonding within the Si–P fragments. For instance, Si and P can form isolated  $\text{SiP}_4$  tetrahedra (as in  $\text{Li}_{14}\text{SiP}_6$ ),<sup>26</sup> corner-sharing tetrahedra (as in  $\text{SiP}_2$ ),<sup>27</sup> and edge-sharing tetrahedra (as in  $\text{Ba}_4\text{Si}_3\text{P}_8$ ).<sup>28</sup> In addition, Si–Si bonds can form to increase the magnitude of negative charge of the overall fragment or to balance the charge.<sup>23</sup> Conversely, P–P bonds can be formed to reduce the negative charge of the fragment. P is typically known for its trigonal pyramidal geometry, but P is versatile and is capable of being undercoordinated. Undercoordinated P atoms represent a way of increasing the magnitude of negative charge. In  $\text{CsBa}_6\text{Si}_{12}\text{P}_{20}\text{Cl}$  (Fig. 1A), due to the large charge of the  $[\text{Ba}_6\text{Cl}]$  polycation, the Si–P framework contains corner sharing as well as edge sharing  $\text{SiP}_4$  tetrahedra with undercoordinated (2-coordinate) P atoms occupying the 48*i* site. The Si–P framework has a repeating fragment of six directionally oriented corner-sharing  $\text{SiP}_4$  tetrahedra (Fig. 1C and D). This fragment is connected to an identical fragment facing the opposite direction through edge-sharing tetrahedra. All Si atoms in the structure are four-coordinate, however, the connectivity of the Si–P fragments leaves large voids in the crystal structure. The first void is filled by Cs. Cs is coordinated by 12 phosphorus atoms that form a cuboctahedron (Fig. 1E) with a volume of  $132.6 \text{ \AA}^3$ . This is comparable to the volume of pentagonal dodecahedron cages in type I clathrates,  $\text{Cs}_8\text{Cd}_{18}\text{As}_{28}$  ( $144.5 \text{ \AA}^3$ ) and  $\text{Cs}_8\text{Ga}_{27}\text{Sb}_{19}$  ( $149.9 \text{ \AA}^3$ ).<sup>29,30</sup> The second void is extremely large with a volume of  $575 \text{ \AA}^3$  and is filled with the  $\text{Cl}@Ba_6$  octahedron (Fig. 1F). The distance between Cl and Ba is 3.40 Å. Each trigonal face of the  $\text{Cl}@Ba_6$  octahedron is capped with a P atom, which forms a cube around the octahedron (Fig. 1G). Furthermore, a truncated octahedron with 24 P atoms at each vertex encapsulates the  $\text{Cl}@Ba_6@P_8$  unit (Fig. 1H). The 8 P atoms forming the cube intersect the center of the hexagonal faces of the truncated octahedron. This giant truncated octahedra share square faces with the cuboctahedra and thus not completely isolated by the silicon phosphorus framework. The truncated octahedron and cuboctahedron pack together in a rock-salt sublattice (Fig. 1B). The distance between the two P atoms in the square face of the cuboctahedron that connects with the truncated octahedron is 5.48 Å. The large channels between Cs and Ba are comparative

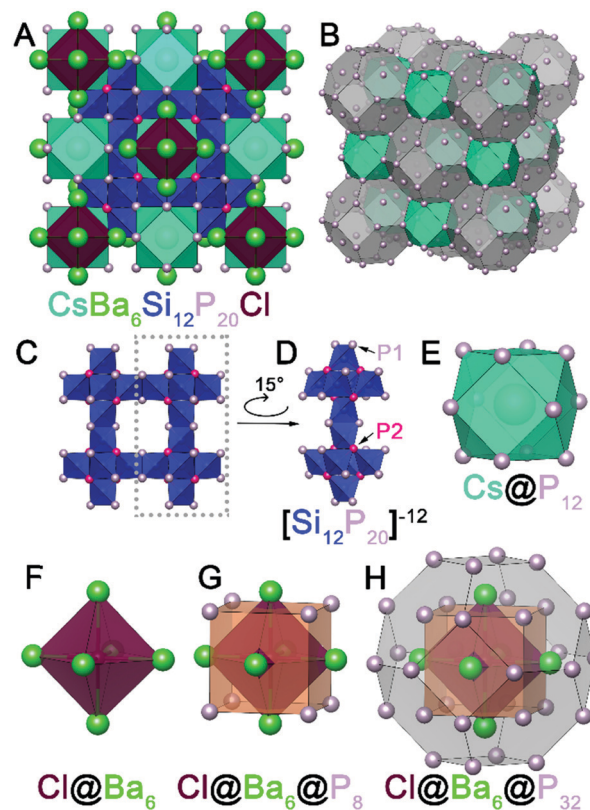
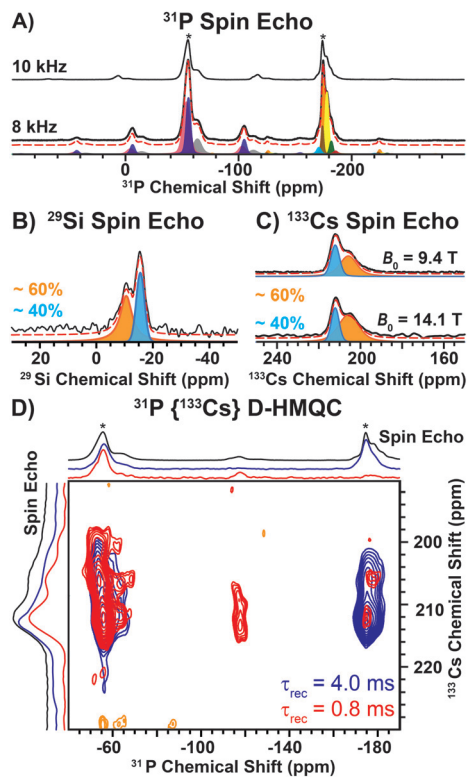


Fig. 1 (A) Unit cell view of  $\text{CsBa}_6\text{Si}_{12}\text{P}_{20}\text{Cl}$  along [100]. (B) Rock-salt packing of truncated octahedra and cuboctahedra. (C) Si–P framework viewed along [100]. (D) Si–P repeating fragment featuring two groups of 6 directionally oriented corner-sharing  $\text{SiP}_4$  tetrahedra. (E)  $\text{Cs}@P_{12}$  cuboctahedron. (F)  $\text{Cl}@Ba_6$  octahedron. (G)  $\text{Cl}@Ba_6$  octahedron encapsulated in a  $P_8$  cube. (H)  $\text{Cl}@Ba_6@P_8$  unit inside of a truncated octahedron formed by 24 P atoms.

to small channel zeolites. Conventional zeolite channels range between 4.2 and 7.4 Å.<sup>31</sup> Another interesting structural feature is that the cation-filled voids are connected in all directions, *i.e.* the channels are three dimensional.

While the atomic assignments from SXRD were made by considering the connectivity of the structure as well as the composition, it should be noted that X-ray diffraction is not sensitive enough to indisputably distinguish Cs from Ba. In  $\text{CsBa}_6\text{Si}_{12}\text{P}_{20}\text{Cl}$ , the best refinement was obtained when Cs solely occupies the 4b site and Ba solely occupies the 24e site. Attempts at refining a mixture of Cs/Ba at either site resulted in unstable refinements due to similarities of Cs and Ba scattering factors. However, when Cs is replaced with Rb, K, or Na with different enough scattering factors the site occupancies of the 4b and 24e sites clearly indicate that the alkali and Ba cations are mixing in both sites. There is a clear trend of the smaller alkali metal avoiding the 4b site in the center of the cuboctahedra and instead shifting to the 24e site, forming shorter A–P distances (Fig. S3 and Table S4, ESI<sup>†</sup>). The smaller alkaline-earth metal, Sr, does not mix with Rb or Cs, which are both larger than Sr, and has yet to be synthesized with Na or K. The iodine containing analogs ( $\text{CsBa}_6\text{Si}_{12}\text{P}_{20}\text{I}$ ,  $\text{RbBa}_6\text{Si}_{12}\text{P}_{20}\text{I}$ ) have





**Fig. 2** (A) 1D  $^{31}\text{P}$  spin echo NMR spectra recorded with a (lower) 8 kHz or (upper) 10 kHz MAS frequency. Asterisks denote isotropic NMR signals. (B) 1D  $^{29}\text{Si}$  spin echo NMR spectrum. (C) 1D  $^{133}\text{Cs}$  spin echo NMR spectra recorded at  $B_0 =$  (upper) 9.4 T or (lower) 14.1 T. Experimental (black solid line) and analytically simulated (red dashed line) spectra are shown. (D) 2D  $^{31}\text{P}\{^{133}\text{Cs}\}$  D-HMQC NMR spectra recorded with either (red) 0.8 ms or (blue) 4 ms of heteronuclear dipolar recoupling applied to the  $^{31}\text{P}$  spins.

additional complexity as the iodine position is partially vacant. To account for the charge imbalance, the Ba is replaced by Rb/Cs making the actual composition close to  $\text{Rb}_{1.1}\text{Ba}_{5.9}\text{Si}_{12}\text{P}_{20}\text{I}_{0.9}$ . To validate atomic assignments of Si and P, as well as understand the cation mixing, we employed magic angle spinning (MAS) solid-state nuclear magnetic resonance (NMR) spectroscopy.

Direct excitation  $^{31}\text{P}$  solid-state NMR spectra reveal two main groups of NMR signals centered at *ca.*  $-56$  and  $-175$  ppm (Fig. 2A). The high frequency  $^{31}\text{P}$  NMR signals ( $-56$  ppm) exhibit larger chemical shift anisotropy (CSA; span ( $\Omega$ )  $\sim 115$  ppm) than the low frequency signals ( $-175$  ppm;  $\Omega \sim 62$  ppm, Table S7, ESI $^\dagger$ ). The magnitude of the CSA is dependent on the local symmetry at the nucleus; symmetric environments give rise to small CSA. Therefore, the  $^{31}\text{P}$  NMR signals at  $-56$  ppm and  $-175$  ppm correspond to the 2- and 3-coordinate P sites, respectively. The ratio of the 2 and 3-coordinate  $^{31}\text{P}$  NMR signals is *ca.* 3 : 2, consistent with the structure determined by SXR (Table S7, ESI $^\dagger$ ). We note that each group of  $^{31}\text{P}$  NMR signals exhibits multiple peaks (shoulders), which likely arises from structural (substitutional) disorder. Interestingly, a direct excitation  $^{29}\text{Si}$  NMR spectrum reveals two relatively broad  $^{29}\text{Si}$  NMR signals at  $-11$  ppm and  $-16$  ppm with relative populations of *ca.* 60 and 40%, respectively (Fig. 2B and Table S8, ESI $^\dagger$ ). In addition, direct

excitation  $^{133}\text{Cs}$  NMR spectra also reveal two sites centered at *ca.* 206 ppm (*ca.* 60%) and 212 ppm (*ca.* 40%) (Fig. 2C and Table S9, ESI $^\dagger$ ). Only one unique Si and Cs site is expected from the SXR structure.

To further probe the two unique  $^{133}\text{Cs}$  NMR signals, we recorded 2D  $^{31}\text{P}\{^{133}\text{Cs}\}$  D-HMQC NMR spectra. The  $^{31}\text{P}\{^{133}\text{Cs}\}$  D-HMQC NMR spectrum recorded with a short duration of heteronuclear dipolar recoupling (0.8 ms) reveals that the 2-coordinate  $^{31}\text{P}$  NMR signals (*ca.*  $-56$  ppm) correlate to both  $^{133}\text{Cs}$  sites (Fig. 2D, red). The short duration of dipolar recoupling primarily probes  $^{31}\text{P}$ - $^{133}\text{Cs}$  spin pairs in close spatial proximity. Closer examination of the 2-coordinate  $^{31}\text{P}$  NMR signal suggests two unique 2-coordinate sites, where the lower or higher frequency  $^{31}\text{P}$  NMR signals correlate with the higher or lower frequency  $^{133}\text{Cs}$  NMR signals, respectively (Fig. S5, ESI $^\dagger$ ). In addition, weak  $^{31}\text{P}$ - $^{133}\text{Cs}$  correlations are observed for the 3-coordinate  $^{31}\text{P}$  NMR signals, where the center of the  $^{31}\text{P}$  NMR signal is shifted to a lower frequency than that observed in the  $^{31}\text{P}$  spin echo NMR spectrum (Fig. 2D, red). It is not surprising that the most intense 3-coordinate  $^{31}\text{P}$  NMR signal ( $-174$  ppm) shows weak correlations in the 2D HMQC spectrum as these P atoms are quite distant from Cs (6.44 Å). However, the lower frequency  $^{31}\text{P}$  shoulder ( $-177$  ppm) has increased intensity in the HMQC spectrum and significantly lower intensity in the  $^{31}\text{P}$  spin echo NMR spectrum as compared to the  $-174$  ppm  $^{31}\text{P}$  NMR signal. Furthermore, the lower frequency  $^{31}\text{P}$  NMR signal ( $-177$  ppm) primarily correlates with the lower frequency  $^{133}\text{Cs}$  NMR signal, suggesting it is in closer spatial proximity to Cs (Fig. 2D). At long durations of heteronuclear dipolar recoupling (4 ms), all  $^{31}\text{P}$  NMR signals reveal correlations to both  $^{133}\text{Cs}$  NMR signals (Fig. 2D, blue). The observation of two unique  $^{29}\text{Si}$  and  $^{133}\text{Cs}$  sites, in addition to the  $^{31}\text{P}\{^{133}\text{Cs}\}$  D-HMQC correlations discussed above, suggests site mixing between Cs and Ba. The  $^{133}\text{Cs}$  NMR signal at *ca.* 206 ppm is assigned to Cs replacing a Ba site based on the correlations observed with the lower frequency 3-coordinate  $^{31}\text{P}$  NMR signal ( $-177$  ppm) in the 2D  $^{31}\text{P}\{^{133}\text{Cs}\}$  D-HMQC spectrum. We note that the  $^{133}\text{Cs}$  NMR signal at *ca.* 206 ppm is broader than the  $^{133}\text{Cs}$  NMR signal at *ca.* 212 ppm, consistent with a more asymmetric environment. A  $^{35}\text{Cl}$  spin echo NMR spectrum reveals a sharp NMR signal assigned to Cl coordinated by 6 Ba atoms (Fig. S4, ESI $^\dagger$ ). In addition, there is a broadened  $^{35}\text{Cl}$  NMR signal, consistent with a more asymmetric environment when Cl is coordinated by both Ba and Cs (Fig. S4, ESI $^\dagger$ ).

Since there are no Si-Si or P-P bonds, the electron balance in the produced compounds can be rationalized either as  $(\text{Cs}^+)(\text{Ba}^{2+})_6(\text{Si}^{4+})_{12}(\text{P}^{3-})_{20}(\text{Cl}^{1-})$  when Si-P bonding is treated as ionic or  $(\text{Cs}^+)(\text{Ba}^{2+})_6(\text{Si}^0)_{12}(\text{P}^0)_8(\text{P}^{1-})_{12}(\text{Cl}^{1-})$  when Si-P bonding is covalent. Band structure calculations underestimated the band gap of materials by 0.4–0.5 eV against experimental values from UV-vis diffuse reflectance spectroscopy (Fig. 3A). For  $\text{CsBa}_6\text{Si}_{12}\text{P}_{20}\text{Cl}$ , the band structure shows a direct band gap of about 1.45 eV at the  $\Gamma$ -point, which correlates with the direct experimental gap shown in the Tauc plot to be 1.92 eV (Fig. S9, ESI $^\dagger$ ). The valence band maximum (VBM) is mostly populated with P states with contributions from Ba, while the conduction band minimum (CBM) has nearly equal contributions from Si,



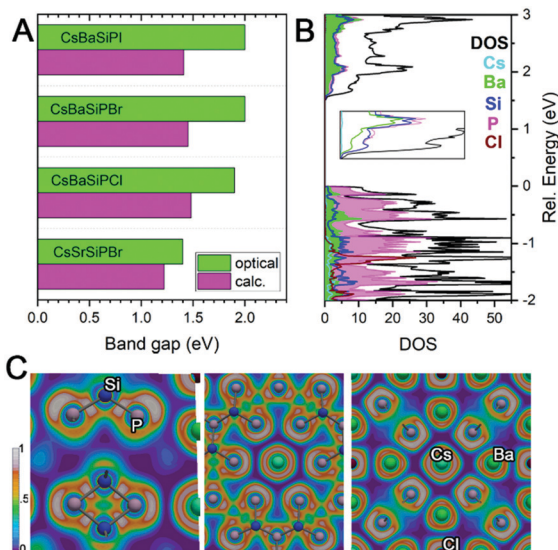


Fig. 3 (A) Comparison of calculated and experimental band gaps. (B) Density of states with inset showing the CBM. (C) ELF visualizations.

P, and Ba. Electron localization function (ELF) analysis (Fig. 3C) found covalent bonds for Si–P interactions and additional electron lone pairs located on P atoms. Cs and Cl appear ionic as demonstrated by the spherical shaped ELF density. The ELF distribution around Ba is not entirely spherical, which indicates weak directed interactions between the Ba and P atoms as in  $\text{Ba}_3\text{S}_4\text{I}_2$ .<sup>32</sup> Because of the lack of states near the VBM and CBM for the A and X, the band gaps are not affected by the substitution of these elements. However, replacing Ba with Sr results in a shrinking of the gap and a transformation from a direct to an indirect bandgap (Fig. S9 and S10, ESI†).

In conclusion, we have synthesized a novel family of semiconductors that appear to be versatile in composition. Their bandgaps range from 1.4 to 2.0 eV which is within the range for photovoltaic, photocatalytic, and radiation detection materials. The large cage-like structure contains unique cluster cations. The Si–P framework which forms the cages has large pores (diameter > 5 Å), similar to zeolite materials. High chemical and thermal stabilities of the reported compounds demonstrate the promise of Si–P frameworks for functional materials in optical and ion transport applications.

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## Conflicts of interest

There are no conflicts to declare.

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